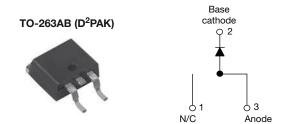


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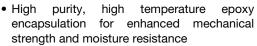
## High Performance Schottky Rectifier, 6 A



| PRODUCT SUMMARY                  |                               |  |  |  |  |  |  |
|----------------------------------|-------------------------------|--|--|--|--|--|--|
| Package                          | TO-263AB (D <sup>2</sup> PAK) |  |  |  |  |  |  |
| I <sub>F(AV)</sub>               | 6 A                           |  |  |  |  |  |  |
| $V_{R}$                          | 35 V, 40 V, 45 V              |  |  |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 0.53 V                        |  |  |  |  |  |  |
| I <sub>RM</sub>                  | 7 mA at 125 °C                |  |  |  |  |  |  |
| $T_J$ max.                       | 175 °C                        |  |  |  |  |  |  |
| Diode variation                  | Single die                    |  |  |  |  |  |  |
| E <sub>AS</sub>                  | 8 mJ                          |  |  |  |  |  |  |

#### **FEATURES**

- 175 °C T<sub>J</sub> operation
- High frequency operation
- · Low forward voltage drop





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

### **DESCRIPTION**

The VS-6TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS |   |             |       |  |  |  |  |  |  |
|-----------------------------------|---|-------------|-------|--|--|--|--|--|--|
| SYMBOL                            | CHARACTERISTICS                             | VALUES      | UNITS |  |  |  |  |  |  |
| I <sub>F(AV)</sub>                | Rectangular waveform                        | 6           | А     |  |  |  |  |  |  |
| V <sub>RRM</sub>                  | Range                                       | 35 to 45    | V     |  |  |  |  |  |  |
| I <sub>FSM</sub>                  | t <sub>p</sub> = 5 μs sine                  | 690         | А     |  |  |  |  |  |  |
| V <sub>F</sub>                    | 6 A <sub>pk</sub> , T <sub>J</sub> = 125 °C | 0.53        | V     |  |  |  |  |  |  |
| T <sub>J</sub>                    | Range                                       | -55 to +175 | °C    |  |  |  |  |  |  |

| VOLTAGE RATINGS                      |                  |               |               |               |       |  |  |  |  |  |
|--------------------------------------|------------------|---------------|---------------|---------------|-------|--|--|--|--|--|
| PARAMETER                            | SYMBOL           | VS-6TQ035SPbF | VS-6TQ040SPbF | VS-6TQ045SPbF | UNITS |  |  |  |  |  |
| Maximum DC reverse voltage           | V <sub>R</sub>   | 25            | 40            | 45            | V     |  |  |  |  |  |
| Maximum working peak reverse voltage | V <sub>RWM</sub> | 35            | 40            | 45            | V     |  |  |  |  |  |

| ABSOLUTE MAXIMUM RATINGS                            |                    |  |   |        |       |  |  |  |
|---|--------------------|--|---|--------|-------|--|--|--|
| PARAMETER   | SYMBOL             | TEST COND  | ITIONS  | VALUES | UNITS |  |  |  |
| Maximum average forward current<br>See fig. 5       | I <sub>F(AV)</sub> | 50 % duty cycle at T <sub>C</sub> = 164 °C                                   | 6   |        |       |  |  |  |
| Maximum peak one cycle non-repetitive surge current | l=a                | 5 µs sine or 3 µs rect. pulse  | Following any rated load condition and with rated | 690    | Α     |  |  |  |
| See fig. 7  | IFSM               | 10 ms sine or 6 ms rect. pulse   | V <sub>RRM</sub> applied                          | 140    |       |  |  |  |
| Non-repetitive avalanche energy                     | E <sub>AS</sub>    | T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.20 A, L = 11.                    | 8   | mJ     |       |  |  |  |
| Repetitive avalanche current                        | I <sub>AR</sub>    | Current decaying linearly to zero Frequency limited by T <sub>J</sub> maximo | 1.20  | Α      |       |  |  |  |

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| ELECTRICAL SPECIFICATIONS                  |                                |  |                                       |       |      |  |  |
|--|--------------------------------|--|---------------------------------------|-------|------|--|--|
| PARAMETER                                  | SYMBOL                         | TEST CO  | VALUES                                | UNITS |      |  |  |
| Maximum forward voltage drop<br>See fig. 1 |                                | 6 A  | T <sub>.1</sub> = 25 °C               | 0.60  |      |  |  |
|  | V <sub>FM</sub> <sup>(1)</sup> | 12 A   | 11=25 0                               | 0.73  | V    |  |  |
|  | VFM (1)                        | 6 A  | T <sub>.1</sub> = 125 °C              | 0.53  | V    |  |  |
|  |                                | 12 A   | 1 J = 125 C                           | 0.64  |      |  |  |
| Maximum reverse leakage current            | I <sub>RM</sub> <sup>(1)</sup> | T <sub>J</sub> = 25 °C                               | V - Potod V                           | 0.8   | mA   |  |  |
| See fig. 2                                 |                                | T <sub>J</sub> = 125 °C                              | V <sub>R</sub> = Rated V <sub>R</sub> | 7     | IIIA |  |  |
| Threshold voltage                          | V <sub>F(TO)</sub>             | T T massimum   |                                       | 0.35  | V    |  |  |
| Forward slope resistance                   | r <sub>t</sub>                 | i j = i j maximum                                    | $T_J = T_J$ maximum                   |       | mΩ   |  |  |
| Maximum junction capacitance               | C <sub>T</sub>                 | V <sub>R</sub> = 5 V <sub>DC</sub> (test signal rang | 400                                   | pF    |      |  |  |
| Typical series inductance                  | L <sub>S</sub>                 | Measured lead to lead 5 mr                           | 8.0                                   | nH    |      |  |  |
| Maximum voltage rate of change             | dV/dt                          | Rated V <sub>R</sub>                                 | 10 000                                | V/µs  |      |  |  |

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width  $<300~\mu s,$  duty cycle <2~%

| THERMAL - MECHANICAL SPECIFICATIONS          |                           |                                   |                                      |             |            |  |  |
|--|---------------------------|-----------------------------------|--------------------------------------|-------------|------------|--|--|
| PARAMETER                                    |                           | SYMBOL                            | TEST CONDITIONS                      | VALUES      | UNITS      |  |  |
| Maximum junction and stora temperature range | ge                        | T <sub>J</sub> , T <sub>Stg</sub> |                                      | -55 to +175 | °C         |  |  |
| Maximum thermal resistance, junction to case |                           | R <sub>thJC</sub>                 | DC operation<br>See fig. 4           | 2.2         | °C/W       |  |  |
| Typical thermal resistance, case to heatsink |                           | R <sub>thCS</sub>                 | Mounting surface, smooth and greased | 0.50        | G/VV       |  |  |
| Approximate weight                           | A                         |                                   |                                      | 2           | g          |  |  |
| Approximate weight                           |                           |                                   |                                      | 0.07        | oz.        |  |  |
| Manusting toward                             | minimum                   |                                   |                                      | 6 (5)       | kgf · cm   |  |  |
| Mounting torque                              | Mounting torque — maximum |                                   |                                      | 12 (10)     | (lbf · in) |  |  |
|  |                           |                                   |                                      | 6TQ03       | 35S        |  |  |
| Marking device                               | Marking device            |                                   | Case style D <sup>2</sup> PAK        | 6TQ040S     |            |  |  |
|  |                           |                                   |                                      | 6TQ045S     |            |  |  |



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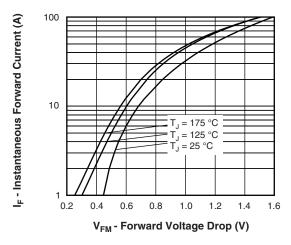


Fig. 1 - Maximum Forward Voltage Drop Characteristics

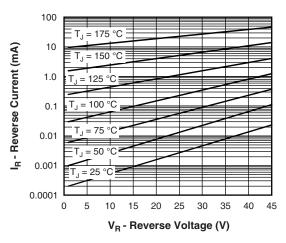


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

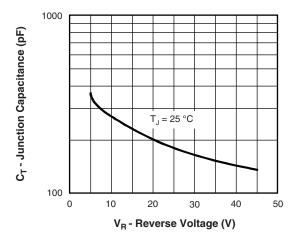


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

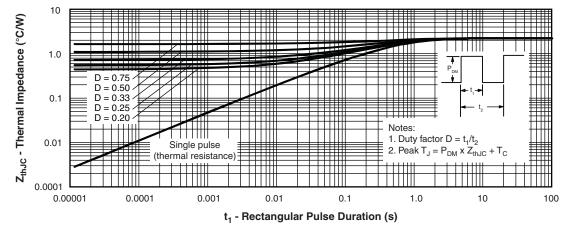


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



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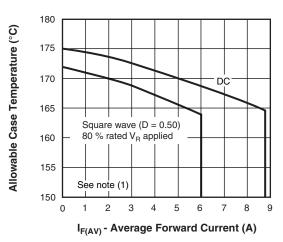


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

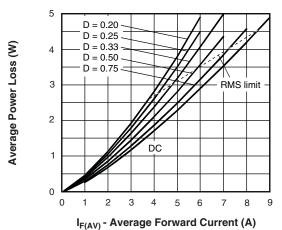


Fig. 6 - Forward Power Loss Characteristics

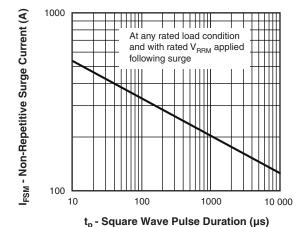


Fig. 7 - Maximum Non-Repetitive Surge Current

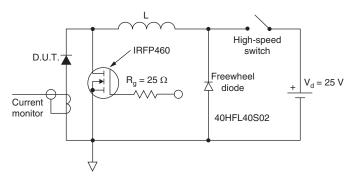


Fig. 8 - Unclamped Inductive Test Circuit

### Note

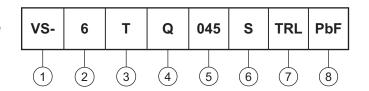
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = 80 \text{ \% rated } V_R \\ \end{array}$ 

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045 = 45 V

### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (6 A)

3 - Package: T = TO-220

4 - Schottky "Q" series 035 = 35 V 5 - Voltage ratings 040 = 40 V

7 - • None = tube (50 pieces)

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

8 - PbF = lead (Pb)-free

| ORDERING INFORMATION (Example) |                   |                        |                                    |  |  |  |  |  |  |
|--------------------------------|-------------------|------------------------|------------------------------------|--|--|--|--|--|--|
| PREFERRED P/N                  | QUANTITY PER REEL | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION              |  |  |  |  |  |  |
| VS-6TQ035SPBF                  | 50                | 1000                   | Antistatic plastic tubes           |  |  |  |  |  |  |
| VS-6TQ035STRRPBF               | 800               | 800                    | 13" diameter plastic tape and reel |  |  |  |  |  |  |
| VS-6TQ035STRLPBF               | 800               | 800                    | 13" diameter plastic tape and reel |  |  |  |  |  |  |
| VS-6TQ040SPBF                  | 50                | 1000                   | Antistatic plastic tubes           |  |  |  |  |  |  |
| VS-6TQ040STRRPBF               | 800               | 800                    | 13" diameter plastic tape and reel |  |  |  |  |  |  |
| VS-6TQ040STRLPBF               | 800               | 800                    | 13" diameter plastic tape and reel |  |  |  |  |  |  |
| VS-6TQ045SPBF                  | 50                | 1000                   | Antistatic plastic tubes           |  |  |  |  |  |  |
| VS-6TQ045STRRPBF               | 800               | 800                    | 13" diameter plastic tape and reel |  |  |  |  |  |  |
| VS-6TQ045STRLPBF               | 800               | 800                    | 13" diameter plastic tape and reel |  |  |  |  |  |  |

| LINKS TO RELATED DOCUMENTS |                          |  |  |  |  |  |
|----------------------------|--------------------------|--|--|--|--|--|
| Dimensions                 | www.vishay.com/doc?95046 |  |  |  |  |  |
| Part marking information   | www.vishay.com/doc?95054 |  |  |  |  |  |
| Packaging information      | www.vishay.com/doc?95032 |  |  |  |  |  |



## Vishay Semiconductors

### D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches



| SYMBOL   | MILLIMETERS |       | INC   | INCHES |       | NOTES | SYMBOL  | MILLIM | ETERS | INC   | HES   | NOTES |
|----------|-------------|-------|-------|--------|-------|-------|---------|--------|-------|-------|-------|-------|
| STIVIBUL | MIN.        | MAX.  | MIN.  | MAX.   | NOIES | NOTES | STWIDOL | MIN.   | MAX.  | MIN.  | MAX.  | NOTES |
| Α        | 4.06        | 4.83  | 0.160 | 0.190  |       |       | D1      | 6.86   | 8.00  | 0.270 | 0.315 | 3     |
| A1       | 0.00        | 0.254 | 0.000 | 0.010  |       |       | Е       | 9.65   | 10.67 | 0.380 | 0.420 | 2, 3  |
| b        | 0.51        | 0.99  | 0.020 | 0.039  |       |       | E1      | 7.90   | 8.80  | 0.311 | 0.346 | 3     |
| b1       | 0.51        | 0.89  | 0.020 | 0.035  | 4     |       | е       | 2.54   | BSC   | 0.100 | ) BSC |       |
| b2       | 1.14        | 1.78  | 0.045 | 0.070  |       |       | Н       | 14.61  | 15.88 | 0.575 | 0.625 |       |
| b3       | 1.14        | 1.73  | 0.045 | 0.068  | 4     |       | L       | 1.78   | 2.79  | 0.070 | 0.110 |       |
| С        | 0.38        | 0.74  | 0.015 | 0.029  |       |       | L1      | -      | 1.65  | -     | 0.066 | 3     |
| c1       | 0.38        | 0.58  | 0.015 | 0.023  | 4     |       | L2      | 1.27   | 1.78  | 0.050 | 0.070 |       |
| c2       | 1.14        | 1.65  | 0.045 | 0.065  |       |       | L3      | 0.25   | BSC   | 0.010 | BSC   |       |
| D        | 8.51        | 9.65  | 0.335 | 0.380  | 2     |       | L4      | 4.78   | 5.28  | 0.188 | 0.208 |       |

### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

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